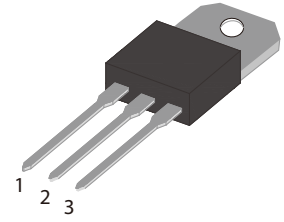


FEATURES

- | High current 25 A RMS current Triac
- | Low thermal resistance
- | High commutation or very high commutation capability
- | RoHS (2002/95/EC) compliant packages
- | UL-94, V0 flammability package resin compliance



TO-220A

APPLICATIONS

- | General purpose motor control circuits
- | Phase control operations in light dimmers and motor speed controllers
- | Home appliances



Schematic Symbol

APPROVALS

| | |
|-------------|------------------------------------|
| RoHS | Compliance with 2011/65/EU |
| HF | Compliance with IEC61249-2-21:2003 |

THE MAIN PARAMETERS

| Symbol | Parameter | Value | Unit |
|--------------|-----------------------------------|-------|------|
| $I_{T(RMS)}$ | RMS on-state current | 25 | A |
| V_{DRM} | Off-state repetitive peak voltage | 800 | V |
| V_{TM} | On-state voltage | 1.5 | V |

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|---|---------------------|----------|------------------|
| Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$) | V_{DRM} | 800 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$) | V_{RRM} | 800 | V |
| RMS on-state current ($T_c=70^\circ\text{C}$) | $I_{\text{T(RMS)}}$ | 25 | A |
| Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$) | I_{TSM} | 250 | |
| I ² t value for fusing ($t_p=10\text{ms}$) | I ² t | 340 | A ² S |
| Critical rate of rise of on-state current ($I_G=2 \cdot I_{\text{GT}}$) | d/d_t | 50 | A/ μs |
| Peak gate current | I_{GM} | 4 | A |
| Average gate power dissipation | $P_{\text{G(AV)}}$ | 1 | W |
| Storage junction temperature range | T_{STG} | -40~+150 | °C |
| Operating junction temperature range | T_j | -40~+125 | |

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Test Condition | Quadrant | Value | | Unit |
|------------------|--|-------------------------|-------------|-------------|------------------|
| | | | CW | BW | |
| I_{GT} | $V_D=12\text{V}, R_L=33\Omega$ | I - II - III | ≤ 35 | ≤ 50 | mA |
| V_{GT} | | | ≤ 1.5 | | |
| V_{GD} | $V_D=V_{\text{DRM}}, R_L=3.3\text{K}\Omega, T_j=125^\circ\text{C}$ | | ≥ 0.2 | | V |
| I_{H} | $I_t=100\text{mA}$ | | ≤ 60 | ≤ 80 | mA |
| I_{L} | $I_G=1.2I_{\text{GT}}$ | I - III | ≤ 70 | ≤ 90 | |
| | | II | ≤ 80 | ≤ 100 | |
| dV_D/dt | $V_D=67\%V_{\text{DRM}}, T_j=125^\circ\text{C}$ | | ≥ 1000 | ≥ 1500 | V/ μs |
| V_{TM} | $I_{\text{TM}}=35\text{A}, t_p=380\mu\text{s}$ | | ≤ 1.5 | | V |
| I_{DRM} | $V_D=V_{\text{DRM}}, V_R=V_{\text{RRM}}$ | $T_j=25^\circ\text{C}$ | ≤ 5 | | μA |
| I_{RRM} | | $T_j=125^\circ\text{C}$ | ≤ 3 | | mA |

THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
|---------------|----------------------|-------|-----------------------------|
| $R_{th(j-c)}$ | Junction to case(AC) | 1.5 | $^{\circ}\text{C}/\text{W}$ |

PARAMETER CHARACTERISTIC CURVE

FIG.1 Maximum power dissipation versus RMS on-state current

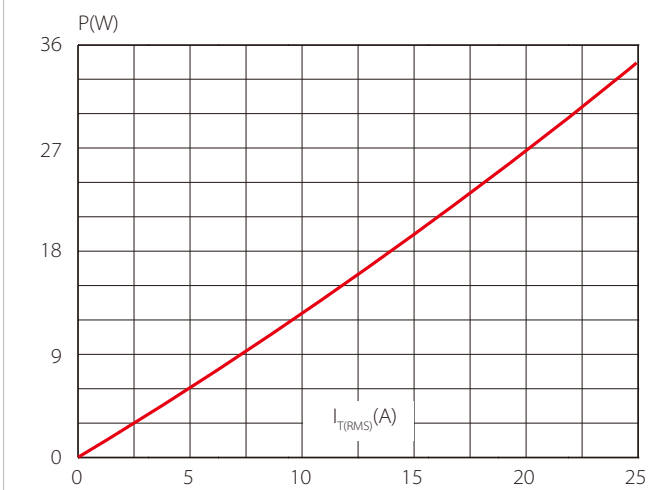


FIG.2: RMS on-state current versus case temperature

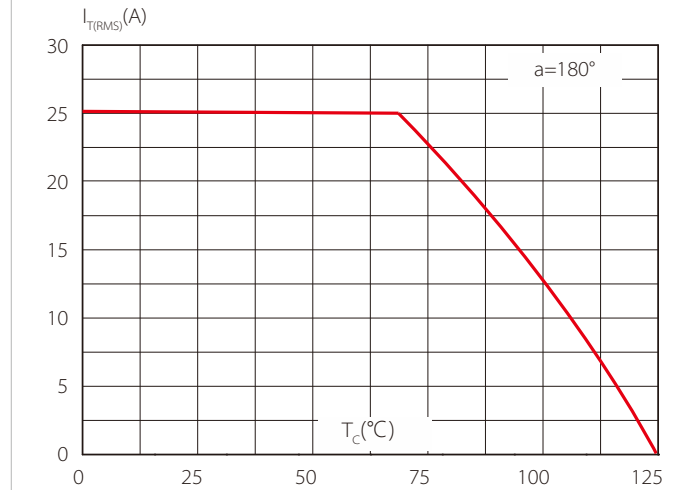


FIG.3: Surge peak on-state current versus number of cycles

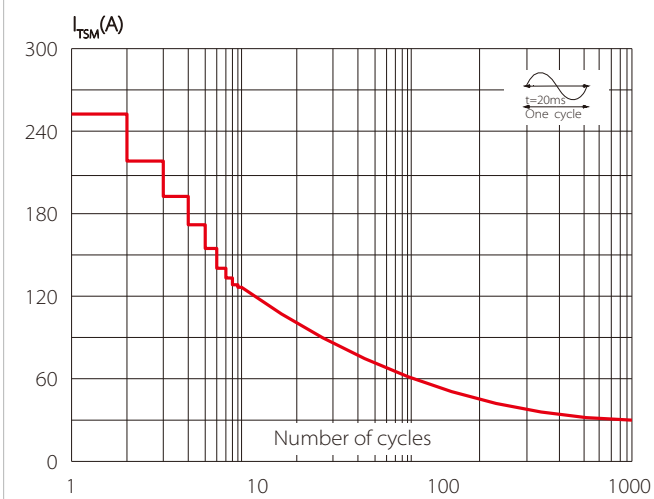


FIG.4 On-state characteristics (maximum values)

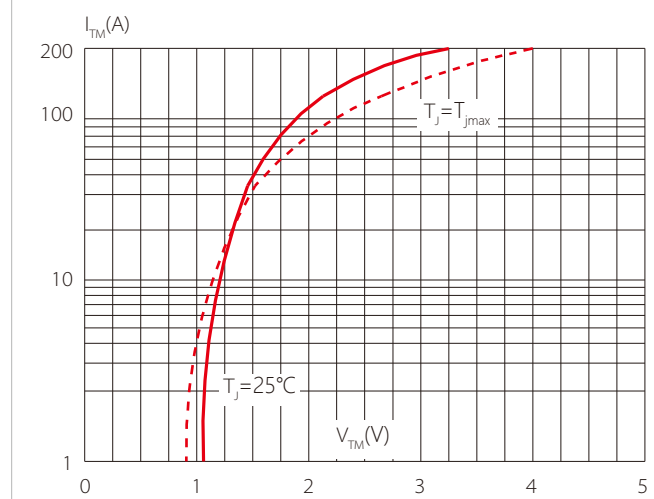


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$ and corresponding value of I^2t ($di/dt < 50\text{A}/\mu\text{s}$)

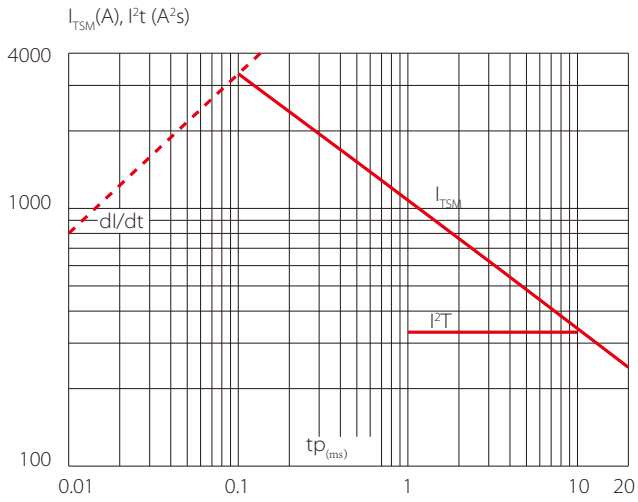


FIG.6 Relative variations of gate trigger current versus junction temperature

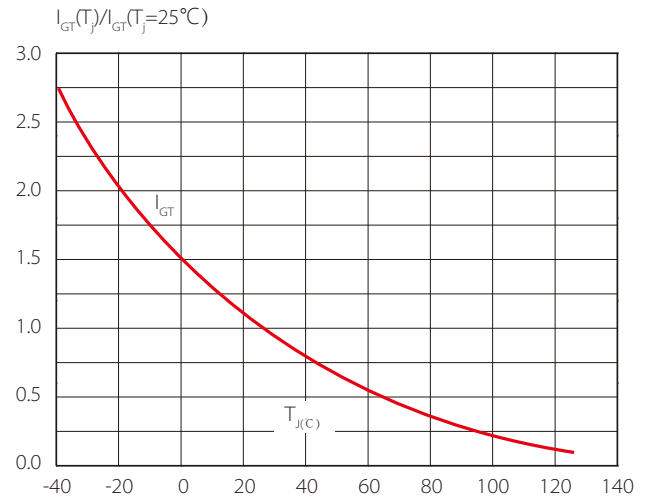


FIG.7 Relative variations of holding current versus junction temperature

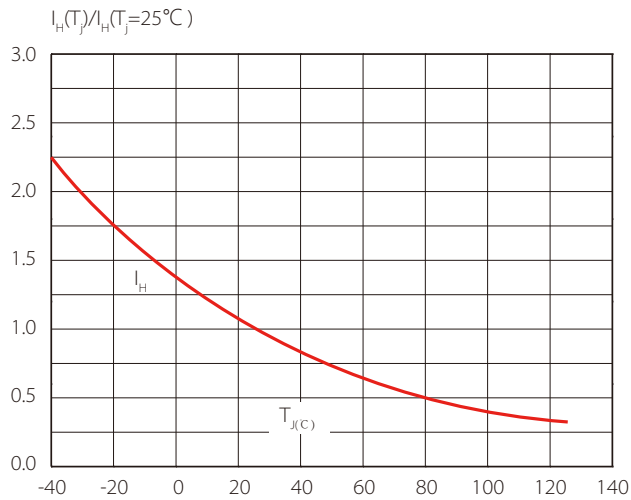
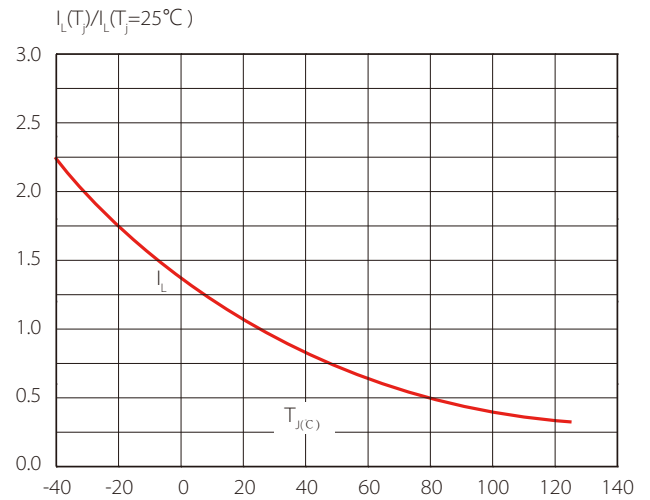
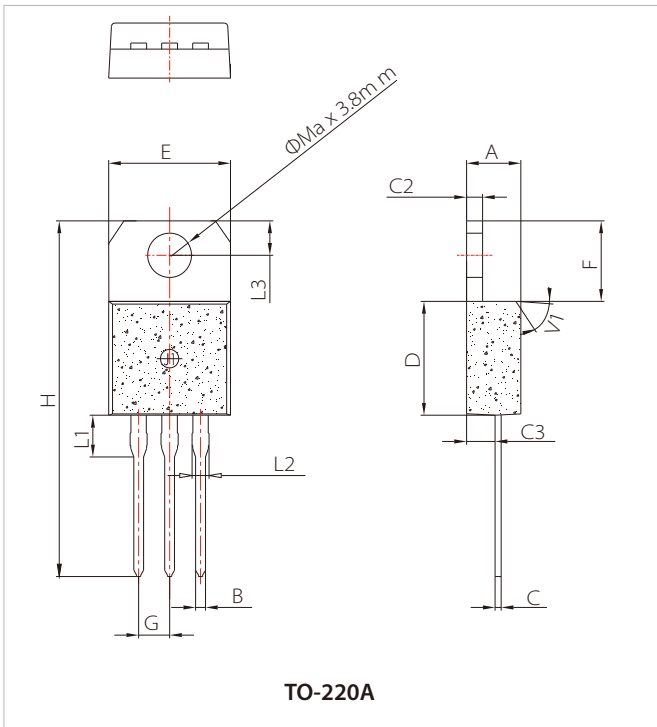


FIG.8 Relative variations of latching current versus junction temperature



PACKAGE MECHANICAL DATA



| Ref. | Dimensions | | | | | |
|------|-------------|------|------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| B | 0.61 | | 0.88 | 0.024 | | 0.035 |
| C | 0.46 | | 0.70 | 0.018 | | 0.028 |
| C2 | 1.21 | | 1.32 | 0.048 | | 0.052 |
| C3 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| D | 8.60 | | 9.70 | 0.339 | | 0.382 |
| E | 9.60 | | 10.4 | 0.378 | | 0.409 |
| F | 6.20 | | 6.60 | 0.222 | | 0.260 |
| G | | 2.54 | | | 0.1 | |
| H | 28.0 | | 29.8 | 1.102 | | 1.173 |
| L1 | | 3.75 | | | 0.148 | |
| L2 | 1.14 | | 1.70 | 0.045 | | 0.067 |
| L3 | 2.65 | | 2.95 | 0.104 | | 0.116 |
| V1 | | 45° | | | 45° | |

ORDERING INFORMATION

| Part Number | Package | Qty/pcs | | |
|----------------|---------|---------|-----------|--------|
| | | Tube | Inner Box | Carton |
| STA25A80CW(BW) | TO-220A | 50 | 1000 | 5000 |

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